



40V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

| V _{(BR)DSS} | R _{DS(ON)} | I _D T _C = +25°C |
|----------------------|---------------------------------------|--|
| 40V | $4.0 \text{m}\Omega$ @ $V_{GS} = 10V$ | 150A |

Features

- Low Input Capacitance
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

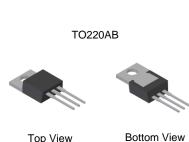
- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

Mechanical Data

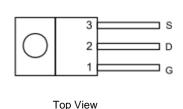
Case: TO220AB

D

- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)







Equivalent Circuit Pin Out Configuration

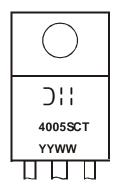
Ordering Information (Note 5)

| Part Number | Case | Packaging |
|--------------|---------|----------------|
| DMNH4005SCTQ | TO220AB | 50 Pieces/Tube |

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



4005SCT = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week (01 to 53)

DMNH4005SCTQ
Document number: DS38859 Rev. 1 - 2

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|--|-----------------|---|-----------------|------------|------|
| Drain-Source Voltage | | | V_{DSS} | 40 | V |
| Gate-Source Voltage | | | V_{GSS} | 20 | V |
| Continuous Drain Current V _{GS} = 10V | Steady State | $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$ | I _D | 150 100 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | | I _{DM} | 90 | Α |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | Is | 80 | Α |
| Avalanche Current (Note 7) L=1mH | | | I _{AS} | 30 | Α |
| Avalanche Energy (Note 7) L=1mH | | | E _{AS} | 500 | mJ |

Thermal Characteristics

| Characteristic | | Symbol | Value | Unit | |
|---|------------------------|-------------------|-------------|------|--|
| Dower Dissipation | $T_C = +25^{\circ}C$ |) | 165 | - W | |
| Power Dissipation | T _C = +70°C | P _D | 100 | | |
| Thermal Resistance, Junction to Case | | R ₀ JC | 0.9 | °C/W | |
| Operating and Storage Temperature Range | | T_{J}, T_{STG} | -55 to +175 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|------|------|---|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 40 | _ | _ | V | $V_{GS} = 0V, I_D = 250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | _ | 1 | μΑ | $V_{DS} = 32V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | _ | _ | ±100 | nA | $V_{GS} = \pm 16V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 8) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | _ | 3 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | _ | 3.4 | 4.0 | mΩ | $V_{GS} = 10V, I_D = 20A$ | |
| Diode Forward Voltage | V _{SD} | _ | _ | 1.2 | V | $V_{GS} = 0V, I_{S} = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 9) | | , | | | | | |
| Input Capacitance | Ciss | _ | 2,846 | _ | | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | |
| Output Capacitance | Coss | _ | 742 | _ | pF | $V_{DS} = 20V, V_{GS} = 0V$ f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | _ | 242 | _ | | I = 1.0WHZ | |
| Gate Resistance | R_{G} | _ | 1.9 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$ | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 48 | _ | | | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | | 23 | _ | nC | 2011 204 | |
| Gate-Source Charge | Q_{gs} | | 9.5 | | IIC | $V_{DD} = 20V, I_D = 20A$ | |
| Gate-Drain Charge | Q_{gd} | | 11.5 | | | | |
| Turn-On Delay Time | t _{D(ON)} | | 6.6 | _ | | | |
| Turn-On Rise Time | t _R | _ | 12.1 | _ | | $V_{DD} = 20V, V_{GS} = 10V,$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ ' | 18.3 | _ | ns | $R_G = 1\Omega$, $I_D = 20A$ | |
| Turn-Off Fall Time | t _F | _ | 4.9 | _ | | | |
| Reverse Recovery Time | t _{RR} | | 29 | _ | ns | 150 31/31 4000/22 | |
| Reverse Recovery Charge | Q _{RR} | | 24 | _ | nC | I _F = 15A, di/dt = 100A/μs | |

6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. 7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C. Notes:

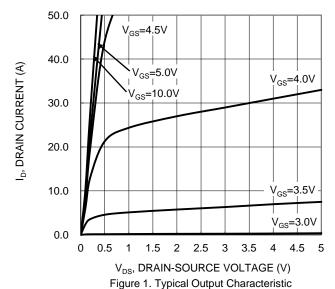
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

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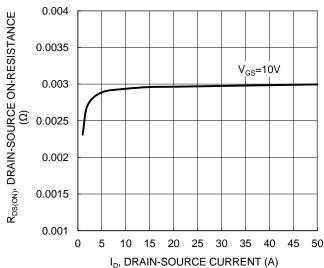


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

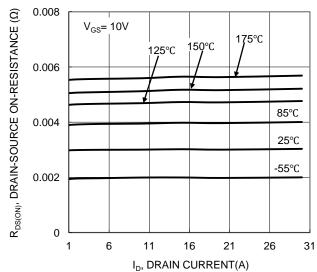
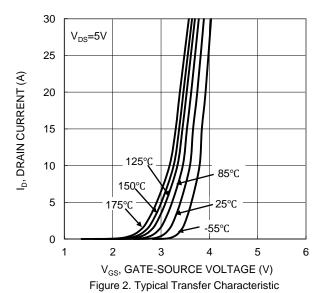
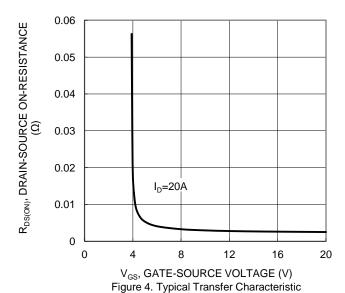
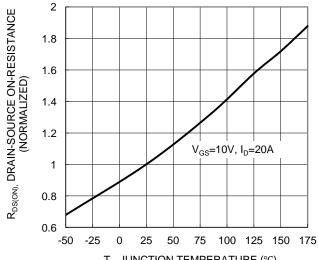


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature







T_J, JUNCTION TEMPERATURE (°C)
Figure 6. On-Resistance Variation with Junction
Temperature



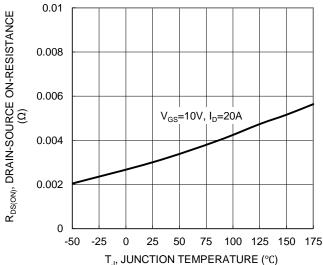


Figure 7. On-Resistance Variation with Junction Temperature

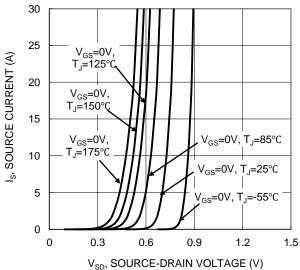


Figure 9. Diode Forward Voltage vs. Current

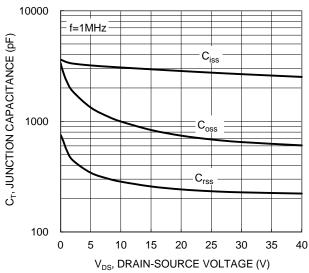


Figure 11. Typical Junction Capacitance

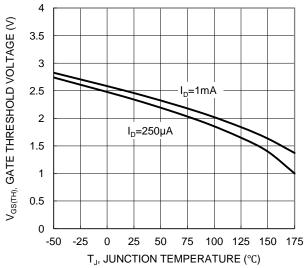


Figure 8. Gate Threshold Variation vs. Junction Temperature

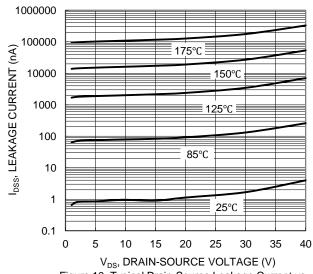


Figure 10. Typical Drain-Source Leakage Current vs. Voltage

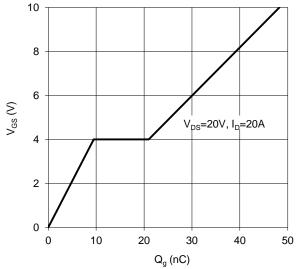


Figure 12. Gate Charge



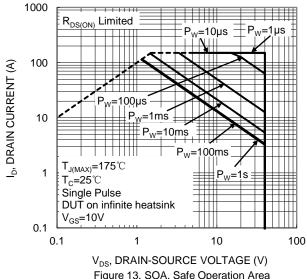


Figure 13. SOA, Safe Operation Area

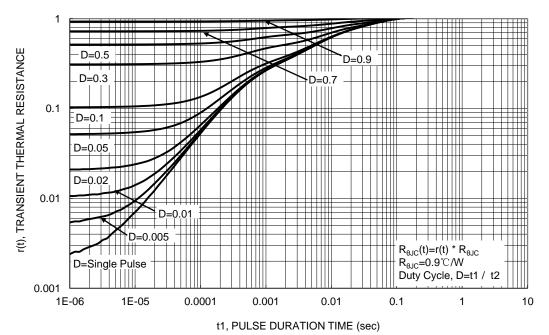


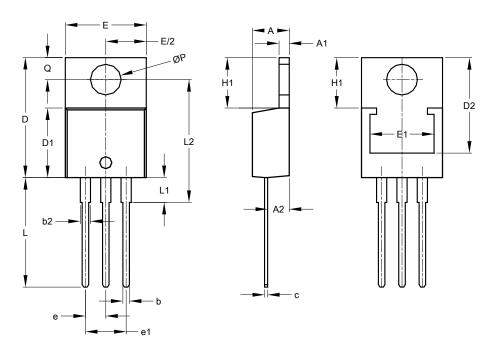
Figure 14. Transient Thermal Resistance



Package Outline Dimensions

 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

TO220AB



| TO220AB | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 3.56 | 4.82 | - | | |
| A1 | 0.51 | 1.39 | - | | |
| A2 | 2.04 | 2.92 | - | | |
| b | 0.39 | 1.01 | 0.81 | | |
| b2 | 1.15 | 1.77 | 1.24 | | |
| C | 0.356 | 0.61 | - | | |
| D | 14.22 | 16.51 | - | | |
| D1 | 8.39 | 9.01 | - | | |
| D2 | 11.45 | 12.87 | - | | |
| e | - | | 2.54 | | |
| e1 | - | 1 | 5.08 | | |
| Е | 9.66 | 10.66 | - | | |
| E1 | 6.86 | 8.89 | - | | |
| H1 | 5.85 | 6.85 | - | | |
| J | 12.70 | 14.73 | - | | |
| ľ | - | 6.35 | - | | |
| L2 | 15.80 | 16.20 | 16.00 | | |
| Р | 3.54 | 4.08 | - | | |
| ø | 2.54 | 3.42 | - | | |
| All Dimensions in mm | | | | | |



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